

# FINAL PRODUCT/PROCESS CHANGE NOTIFICATION # 20306

Generic Copy

#### Issue Date: 04-Dec-2013

TITLE: Wafer fab expansion of TMOS7 devices at ON Semiconductor fab location in Niigata, Japan.

### PROPOSED FIRST SHIP DATE: 04-Mar-2014

### AFFECTED CHANGE CATEGORY(S): ON Semiconductor Wafer Fab

#### FOR ANY QUESTIONS CONCERNING THIS NOTIFICATION:

Contact your local ON Semiconductor Sales Office or following contact Product Engineers:

Sew Seng Tam<<u>SewSeng.Tam @onsemi.com</u>> Mohd Hezri Abu Bakar<<u>MohdHezri.AbuBakar@onsemi.com</u>>

**SAMPLES:** Contact your local ON Semiconductor Sales Office

#### ADDITIONAL RELIABILITY DATA: Available

Contact your local ON Semiconductor Sales Office or Reliability Engineer Donna Scheuch<<u>Donna.Scheuch@onsemi.com</u>>

#### NOTIFICATION TYPE:

Final Product/Process Change Notification (FPCN)

Final change notification sent to customers. FPCNs are issued at least 90 days prior to implementation of the change.

ON Semiconductor will consider this change approved unless specific conditions of acceptance are provided in writing within 30 days of receipt of this notice. To do so, contact <quality@onsemi.com>.

#### DESCRIPTION AND PURPOSE:

This FPCN announces the planned capacity expansion of ON Semiconductor's wafer operations of TMOS7 products to their facility in Niigata Japan.

Upon the expiration of this FPCN, TMOS7 devices may be processed at either Niigata or existing location. These products have been qualified to commodity/commercial requirements. These products will continue being Pb-free, Halide free and RoHS compliant.

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## **RELIABILITY DATA SUMMARY:**

## Reliability Test Results:

### NTDV20P06LT4G

Test		Condition	Duration	Results
HTGB	High Temperature Gate Bias	175C, 100% Rated Vgss	1008 hr	0/240
HTRB	High Temperature Reverse Bias	175C, 80% rated Vdss	1008 hr	0/240
		On/off = 2 min		
IOL - PC	Intermittent Operating Life + PC	Ta=+25°C, delta Tj=100°C	7,500 cyc	0/240
TC - PC	Temperature Cycling + PC	-55 to + 150C	1000 cyc	0/240
	High Humidity High Temp Rev Bias +			
H3TRB – PC	Preconditioning	Ta=85°C, 85% RH, 80% rated	504 hr	0/240
AC- PC	Autoclave + PC	121°C/100% RH/15psig	96 hr	0/240
NTB45N06T4G				
HTGB	High Temperature Gate Bias	175C, 100% Rated Vgss	1008 hr	0/80
HTRB	High Temperature Reverse Bias	175C, 80% rated Vdss	1008 hr	0/80
		On/off = 3.5 min		
IOL - PC	Intermittent Operating Life + PC	Ta=+25°C, delta Tj=100°C	8572 cyc	0/80
TC - PC	Temperature Cycling + PC	-55 to + 150C	1000 cyc	0/80
	High Humidity High Temp Rev Bias +			
H3TRB – PC	Preconditioning	Ta=85°C, 85% RH, 80% rated	504 hr	0/80
AC- PC	Autoclave + PC	121°C/100% RH/15psig	96 hr	0/80
NTB25P06T4G				
HTGB	High Temperature Gate Bias	175C, 100% Rated Vgss	1008 hr	0/80
HTRB	High Temperature Reverse Bias	175C, 80% rated Vdss	1008 hr	0/80
		On/off = 3.5 min		
IOL - PC	Intermittent Operating Life + PC	Ta=+25°C, delta Tj=100°C	8572 cyc	0/80
TC - PC	Temperature Cycling + PC	-55 to + 150C	1000 cyc	0/80
	High Humidity High Temp Rev Bias +			
H3TRB – PC	Preconditioning	Ta=85°C, 85% RH, 80% rated	504 hr	0/80
AC- PC	Autoclave + PC	121°C/100% RH/15psig	96 hr	0/80
BSS1221T1G				
	High Tomporatura Cata Piac	1EOC 100% Pated Vass	501 hr	0/240
	High Temperature Boyerse Bias	150C, 100% Rated Vgss	504 m	0/240
IIIND			504 m	0/240
	Intermittant Operating Life + BC	On/off = 2 min Ta=+25°C dolta Ti=100°C	7500 сис	0/240
	Temperature Cycling + PC	$-55 t_0 + 1500$	500 cyc	0/240
		-JJ (U T IJUC	σουτγι	0/240
H3TRB - PC	High Humidity High Temp Rev Blas + Preconditioning	Ta=85°C 85% RH 80% rated	504 hr	0/240
		121°C/100% RH/15nsig	96 hr	0/240
		TET CLTOON VULLTDhald	30 11	0/240



## FINAL PRODUCT/PROCESS CHANGE NOTIFICATION # 20306

#### BVSS123LT1G

Test		Condition	Duration	Results
HTGB	High Temperature Gate Bias	150C, 100% Rated Vgss	504 hr	0/80
HTRB	High Temperature Reverse Bias	150C, 80% rated Vdss	504 hr	0/80
IOL - PC TC - PC	Intermittent Operating Life + PC Temperature Cycling + PC	On/off = 2 min Ta=+25°C, delta Tj=100°C -55 to + 150C	7500 сус 500 сус	0/80 0/80
H3TRB – PC AC- PC	High Humidity High Temp Rev Bias + Preconditioning Autoclave + PC	Ta=85°C, 85% RH, 80% rated 121°C/100% RH/15psig	504 hr 96 hr	0/80 0/80

### **ELECTRICAL CHARACTERISTIC SUMMARY:**

There are no changes in electrical characteristics; product performance meets data sheet specifications. Characterization data is available upon request.

### CHANGED PART IDENTIFICATION:

Products having work week 08, 2014 and newer may have die coming from Niigata or existing fab.

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## List of affected General Parts:

BS170G BS170RLRAG BSS123LT1G BSS138LT1G BSS138LT3G MMBF170LT1G NTB25P06T4G NTB45N06T4G NTB5605PT4G NTD18N06LT4G NTD20N06T4G NTD20P06LT4G NTD2955-1G NTD2955G NTD2955T4G NTD3055L104-1G NTD3055L104T4G NTF2955T1G NTF3055L108T1G NTP2955G